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Dispersed nickel sulfate (NiSO₄) microclusters on Si substrates were fragmented by pulsed excimer laser irradiation to serve as catalysts for carbon nanotube/nanofiber (CNT/CNF) growth. At proper fluences, NiSO₄ clusters were pulverized into nanoparticles. The sizes of clusters/nanoparticles were found to be dependent on laser fluence and laser pulse number. By increasing the laser fluence from 100 to 300 mJ/cm², the size of disintegrated particles decreased drastically from several micrometers to several nanometers. It was found that laser-induced disintegration of as-dispersed NiSO₄ clusters was mainly due to physical fragmentation by transient thermal expansion/contraction. Thermal melting of nanoparticles in a multipulse regime was also suggested. Hot-filament chemical vapor deposition (HFCVD) was used for growth of CNTs from the pulsed-laser treated catalysts. For samples irradiated at 100 and 200 mJ/cm², CNFs were dominant products. These CNFs grew radially out of big NiSO₄ clusters, forming dendritic CNF bunches. For samples irradiated at 300 mJ/cm², dense multiwalled carbon nanotubes (MWCNFs) with uniform diameters were obtained. It is suggested that elemental Ni was formed through thermal decomposition of NiSO₄ clusters/nanoparticles during HFCVD. The size and the shape of the Ni aggregation, which were determined by the initial size of NiSO₄ clusters/nanoparticles, might affect the preference in the synthesis of CNTs or CNFs. © 2006 American Institute of Physics.

I. INTRODUCTION

In the past decade, carbon nanotubes (CNTs) have been widely studied due to their remarkable physical properties. A large variety of applications, such as field emission displays, nanoelectronic transistors and sensors, require well-controlled fabrication of high-quality CNTs. Current CNT synthesis methods include laser ablation, arc discharge, thermal chemical vapor deposition (CVD), plasma-enhanced CVD (PECVD), hot-filament CVD (HFCVD), and laser-assisted CVD. In most processes, optimization of catalyst preparation is one of the key steps to grow CNTs with desired diameters and size distributions. Conventional catalyst preparation methods include thermal annealing of Ni, Co, Fe thin films prepared by sputtering and electron beam evaporation. Solution-based catalysts were also successfully developed to obtain single-walled CNTs. Plasma ion bombardment of metallic thin films for nanometallic catalysts was also developed, especially for PECVD synthesis of CNTs. Generally, monodispersed and uniformly distributed nanocatalysts are desirable for catalytic growth of CNTs.

Recently, there is an increasing interest in pulsed-laser processing of nanoparticles. Nanocatalysts were fabricated by excimer laser ablation of thin transitional metal films for CNT growth. Due to the surface plasmon resonance of metallic nanoparticles under laser irradiation, monodispersed metallic particles with tunable particle sizes can be generated by laser irradiation at different wavelengths. One of the advantages of pulsed-laser processing over conventional thermal annealing is that it only induces transient temperature increase at the sample surface. Therefore, universal heating of samples can be avoided. In addition, pulsed-laser processing is an ultrafast process and can be performed in ambient atmosphere.

In this study, we demonstrated a method using pulsed excimer laser to generate NiSO₄ nanoparticles as catalysts for CNF/CNT growth. CNTs grown from nanocatalysts, which were generated under optimized laser parameters, were highly uniform in diameters. In the investigation of mechanisms in laser pulverization of NiSO₄ clusters, we found that the process was mainly a physical process of laser fragmentation. Effects of initial NiSO₄ cluster/nanoparticles size on catalytic CNT/CNF growth were also investigated.

II. EXPERIMENT

A 0.1 N NiSO₄ solution was prepared by dissolving 1.3 g of NiSO₄·H₂O in 50 ml deionized (DI) water by sonication. Silicon substrates were ultrasonically cleaned in acetone and methanol sequentially to remove organic contaminations. A thin native oxide was kept on the Si substrates to ensure that the substrates were hydrophilic so that the NiSO₄ solution could be uniformly adsorbed on the substrate surfaces. Cleaned silicon substrates were dipped into the

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NiSO₄ solution and blown dry using compressed air. A monolayer of NiSO₄ microclusters were then formed on the Si substrates. A KrF excimer laser (Lambda Physik Compex 205, wavelength=248 nm, pulse duration=23 ns) was used to break the NiSO₄ clusters into smaller clusters and nanoparticles, as illustrated in Fig. 1(a). In this study, the laser energy ranged from 128 to 380 mJ/pulse, with beam sizes from 0.3 to 3.8 cm². The laser fluences and pulse numbers were in ranges of 100 – 300 mJ/cm² and 5–30 pulses, respectively, with the repetition rate kept at 5 Hz. The samples after laser treatment were placed in a hot-filament vacuum chamber, as shown in Fig. 1(b). The chamber was first pumped to a base pressure of 1×10⁻⁴ Torr. The samples were then back heated to 480 °C before carbon-feedstock gases were introduced into the chamber. Ammonia and acetylene (NH₃/C₂H₂) gas mixture, with a volume ratio of 3, was introduced into the chamber. During the process, reaction pressure was kept at 10±1 Torr. A tungsten filament was kept about 4 mm above the substrate surface. During the process, the filament temperature was kept at around 1400 °C. An atomic force microscope (Digital Instruments Nanoscope IIIa Dimension 3100 SPM) was used for characterization of the laser-pulverized NiSO₄ nanoparticles. Statistical size distributions of clusters and nanoparticles were analyzed by a computer software “Image J.”²² A Hitachi S-4700 field-emission scanning electron microscope was used to investigate the morphologies of NiSO₄ clusters/particles and CNTs/CNFs. Energy dispersive x-ray (EDX) analysis was carried out in a Hitachi S3000N VP-SEM for qualitative elemental analysis. During the EDX measurements, the acceleration voltage and scanning window were fixed to 20 kV and 200×400 nm, respectively. A FEI Tecnai G2 F30 Su-}

![Excimer Laser setup](image)

**FIG. 1.** Experimental setup of (a) laser pulverization of NiSO₄ clusters by focused excimer laser and (b) hot-filament CVD system for CNT/CNF growth.

![SEM micrographs](image)

**FIG. 2.** SEM micrographs of laser-irradiated samples at different fluences. (a) and (b) 100 mJ/cm², (c) and (d) 200 mJ/cm², and (e) and (f) 300 mJ/cm². Pulse numbers were fixed at 30 pulses. The inset of (f) is an AFM image of a typical grey island, indicated by an arrow shown in (f).

pertwin field-emission gun scanning transmission electron microscope (FEG STEM) operating at 300 kV was used for high-resolution TEM (HRTEM) characterization.

### III. RESULTS AND DISCUSSION

#### A. Laser pulverization of NiSO₄ microclusters

Figure 2 shows the SEM micrographs of silicon substrates dispersed with NiSO₄ clusters after laser irradiation at 100, 200, and 300 mJ/cm² for 30 pulses. Figures 2(a) and 2(b) show samples irradiated at a fluence of 100 mJ/cm² for 30 pulses. As shown in Fig. 2(a), NiSO₄ clusters with sizes ranging from 100 nm to 10 μm were sporadically dispersed on the silicon surface. A close-up view of a cluster in Fig. 2(a) is shown in Fig. 2(b). The shape of the NiSO₄ cluster after laser irradiation was cabochon-like bead, with a convex top and a flat back. Atomic force microscopy (AFM) characterization indicates that the diameters and thicknesses were in the order of a few micrometers and hundreds of nanometers, respectively. Notice that the size distribution of clusters were similar to that of the as-dispersed samples, which indicates that NiSO₄ clusters remained almost intact under laser irradiation at 100 mJ/cm² for 30 pulses. Figures 2(c) and 2(d) show the SEM micrographs of samples irradiated at 200 mJ/cm² for 30 pulses. The Si surface was covered with disintegrated particles. The particle sizes varied in a wide range and the shapes were irregular. As shown in Fig. 2(e), the dark region corresponds to a big cluster of NiSO₄ as-deposited from the solution. With a fluence of 300 mJ/cm² and a pulse number of 30, the surface of the NiSO₄ cluster was roughened, showing densely distributed nanoparticles. A close-up view in Fig. 2(f) shows that there are two types of
particles: irregular-shaped submicrometer-sized clusters and nanoparticles with diameters approximately 10–20 nm. From the AFM image (the inset of Fig. 2), the irregular sub-100 nm clusters were actually composed of nanoparticles, with diameters approximately equal to or less than 20 nm. It is suggested that at the initial several pulses, submicrometer-sized clusters were formed as the fragments of laser disintegrated microclusters. Nanoparticles could be generated from the subsequent bombardments of laser pulses.

Figures 3(a)–3(c) show the statistical size distribution of particles under laser irradiation at fluences of 100, 200, and 300 mJ/cm², respectively. Figure 3(d) shows the average size of particles as a function of laser fluence. At the fluences of 100, 200, and 300 mJ/cm², the average sizes of particles were 4.5, 1.1, and 0.015 μm, respectively. From the morphology changes in NiSO₄ clusters and the statistical analysis, we found that increase in the laser fluences could effectively disintegrate large clusters into much smaller nanoparticles. Nanoparticles with a small size variation could be obtained.

Figure 4 shows SEM micrographs of NiSO₄ clusters irradiated with different pulse numbers at a fluence of 300 mJ/cm². Figures 4(a) and 4(b) show the morphology of the sample irradiated for 5 pulses. NiSO₄ clusters were partially disintegrated. A 3 μm NiSO₄ cluster remained intact, whereas laser-induced pulverization did effectively break smaller clusters (up to 1–2 μm) into nanoparticles. When the pulse number was increased to 15, large numbers of NiSO₄ clusters were broken into pieces as shown in Fig. 4(c). Figure 4(d) shows the average size of the nanoparticles as a function of laser pulse number. The average sizes of the particles on the samples irradiated for 5, 15, and 30 pulses, were found to be 17, 16, and 11 nm, respectively. This indicates that under repeated laser shot there was only a moderate decrease in the particle size. The ultimate size of the nanoparticles was directly dependent on the incident laser fluence. However, sufficient pulses are required to disintegrate NiSO₄ microclusters into nanoparticles thoroughly when NiSO₄ clusters are large.

B. Mechanism of laser-induced pulverization of NiSO₄

The mechanisms of laser-material interaction depend on the laser wavelength, pulse duration and fluence. In a nanosecond pulsed-laser ablation regime (corresponding to a fluence from several to tens of joules per square centimeter), thermal, electronic, and hydrodynamic sputtering are major
mechanisms responsible for substrate damages and material ejections. In some cases, wide-band-gap materials such as LiF (Refs. 27 and 28) can be ablated both electronically and hydrodynamically, although the photon energy is smaller than the band gap of the material (excimer laser at 248 and 193 nm, corresponding to photon energy of 5 and 6.4 eV respectively; LiF band gap: 13.6–14.5 eV). At a relatively lower laser fluence (in the order of 10–100 mJ/cm², below the ablation threshold), photothermal melting, photochemical decomposition, and transient thermal shock fragmentation are among the main mechanisms.

In this study, EDX elemental analysis of NiSO₄ clusters before and after laser irradiation was carried out to qualitatively examine the possible products under laser irradiation. Both nickel and sulfur were detected from samples irradiated at fluences from 100 to 300 mJ/cm². A coarse estimation of nickel and sulfur atomic ratio indicated that the amount of sulfur was quite similar as that of nickel on the sample surfaces irradiated with different fluences and pulses. Since thermal decomposition of NiSO₄ would release SO₂ and O₂ gases and result in a much higher Ni/S ratio, it is suggested that under the laser fluences used in the experiments, direct thermal decomposition and melting were not the main mechanisms for nanoparticles generation. Instead, physical pulverization played a main role in the generation a large portion of disintegrated subclusters and nanoparticles composed of nearly stoichiometric NiSO₄.

To further investigate the fundamentals of this laser fragmentation process, one-dimensional heat transfer in laser irradiation on silicon was calculated using a computer program called “Simulation of Laser Interaction with Matter” (SLIM) developed by Singh et al. in which an implicit finite difference scheme is used to solve the heat flow equation. The validity of using this simplified model to estimate the surface temperature of the system was based on the fact that SiO₂ and NiSO₄ are highly transparent at 248 nm. Considering the fact that sporadically distributed NiSO₄ clusters (around 100 nm thick) have a relatively small surface coverage on the silicon substrate than the continuous film, we neglected the laser energy absorbed in NiSO₄ as a coarse approximation. The temporal profile of the incident laser was modeled to be a Gaussian function with a pulse width of 23 ns. In Fig. 5, peak temperatures for single pulse irradiation at fluences of 100, 200, and 300 mJ/cm² are calculated to be 150, 260, and 395 °C, respectively, which are much lower than the thermal decomposition temperature of NiSO₄ around 849 °C. As indicated previously, NiSO₄ disintegration in this study could be due to the transient thermal ex-
pansion of the Si substrates, which was similar to the mechanism of dry laser cleaning.\textsuperscript{34} At the interface of NiSO\textsubscript{4} clusters and Si surfaces, the adhesion force was mainly van der Waals force. Fast thermal expansion of the silicon substrates after laser irradiation could induce deformations in the normal direction. Zhen \textit{et al.} calculated the surface deformation, velocity and acceleration of silica particles on Si substrates when the SiO\textsubscript{2} spheres/Si system was under excimer laser irradiation.\textsuperscript{34} It was found that the surface deformation, velocity and acceleration increased with the transient temperature increase. At a transient maximum temperature around 400 °C (approximately the same as the temperature at 300 mJ/cm\textsuperscript{2} in this study), a maximum surface deformation, velocity and acceleration were found to be 1 nm, 12 cm/s, and 4 \times 10\textsuperscript{9} cm/s\textsuperscript{2}, respectively. Silica particles with diameters from 1 to 5 \mu m can jump around several millimeters above the substrate surface during laser cleaning.\textsuperscript{34} In this study, NiSO\textsubscript{4} clusters may crack and break into irregular shaped subclusters due to the fast thermal expansion of the substrates under excimer laser irradiation. Although the physical thermal transient expansion was suggested to be the main mechanism responsible for NiSO\textsubscript{4} pulverization, we cannot exclude the possibility of melting of NiSO\textsubscript{4} nanoparticles under irradiation of multiple pulses. The melting point of nano-clusters might be much lower than the bulk material. With multipulse irradiation, local decomposition at defects would result in Ni rich areas, which might initiate enhanced absorption of laser energy and induce melting. Further characterizations of the products under such multipulse irradiation will be carried out to discover and differentiate the underlying entangling mechanisms.

C. Catalytic growth of CNTs/CNFs

Figure 6 shows the SEM micrographs of CNTs/CNFs grown from the catalysts prepared with different laser fluences. Figures 6(a) and 6(b), corresponding to laser irradiation for 30 pulses at 100 mJ/cm\textsuperscript{2}, show that large amount of CNTs/CNFs grew out of NiSO\textsubscript{4} microclusters and bundled into cauliflower-like CNT/CNF islands. Figures 6(c) and 6(d) show the SEM micrographs of CNTs/CNFs grown from the catalysts prepared at 200 mJ/cm\textsuperscript{2} for 30 pulses. Smaller bunches of dendritic CNTs/CNFs were found on the silicon substrate sporadically, with average diameters of individual fibers ranging from 50 to 100 nm. A similarity among CNTs/CNFs shown in Figs. 6(a)–6(d) is that they grew almost radially outward, with their base rooted at the original NiSO\textsubscript{4} microclusters. Figures 6(e) and 6(f) show CNTs/CNFs grown from the catalysts prepared at 300 mJ/cm\textsuperscript{2} for 30 pulses. CNT/CNF islands and bunches were not observed. Instead, a large area of substrate was densely covered by CNTs/CNFs with diameters ranging from 10–20 nm. In order to investigate the structures of the CNTs/CNFs, HRTEM was used for morphology characterization and electron diffraction. As shown in Figs. 7(a) and 7(b), carbon fibers with solid interior structures were identified for samples irradiated at 200 mJ/cm\textsuperscript{2} for 30 pulses. Ni particles (dark particles) were embedded in the tips of CNTs, with the size similar to the diameter of CNFs. Both herringbone (or fishbone) type and bamboo type (indicated by the arrows) were identified. The corresponding selected-area electron diffraction pattern showed (0002) and (1\bar{1}00) graphene planes (corresponding to stacked graphitic layers in CNFs) and (200) nickel plane respectively. Figures 7(c) and 7(d) show the TEM micrograph and convergent beam electron diffraction pattern of CNTs grown from the sample irradiated at 300 mJ/cm\textsuperscript{2} for 30 pulses. External diameters of CNTs with hollow cylinders were in a range of 10–20 nm. As shown in Fig. 7(d), an electron beam with diameter of 8 nm was focused on a single tube. Graphite (0002) and (000\bar{2}) were identified, indicating vertical planes of aligned CNTs. (1\bar{1}00) graphite plane was also identified in Fig. 7(d).

CNTs and CNFs are similar two-dimensional stacking graphene structures, with different angles between fiber axis and graphene sheet stacking direction.\textsuperscript{35} The former refers to graphene sheets forming cylinders, whereas the latter refers
to cone- and cup-structured graphene stacking. CNFs are found to have similar electronic and mechanical properties as multiwalled carbon nanotubes (MWCNT). Today, diffusion model is widely accepted for catalytic growth of both CNFs and CNTs, which originated from the vapor-liquid-solid mechanism for growth of whiskers currently known as fibers back to the 1960s. As described in diffusion model, CNF/CNT deposition process usually consists of three steps: First, reactant carbon feedstock molecules (hydrocarbon or carbon containing compounds) adsorb and decompose on the surface of a catalyst; second, carbon species dissolve or diffuse into catalyst particles (usually in a liquid state); finally, carbon precipitates on opposite surface of the catalyst forming nanofiber/nanotube structures. The growth modes for CNTs and CNFs include both tip-type and base-type. However, difference in the growth behavior between CNFs and CNTs is still not fully understood. Nevertheless, Ni particles as catalysts have been widely studied for catalytic growth for both CNFs and MWCNT. It is found that the contact angle of the catalyst with the supporting surface greatly affects the growth behavior. When the catalyst has multifaceted shape (such as cone-like structures) with flat surfaces facing substrates, graphene layers tend to bend parallel to the flat surface of the catalysts. In this manner, fishbone-type CNFs will be formed by graphene layer precipitation directly under these surfaces, which lifted the Ni particles from the surface.

From SEM and TEM micrographs, we found that the initial size of NiSO₄ clusters/nanoparticles determined diameters of CNTs/CNFs. For NiSO₄ micro- or submicrometer-clusters, corresponding to samples irradiated at 100 and 200 mJ/cm², thermal decomposition of NiSO₄ took place during the CNT/CNF growth in the HFCVD chamber. In the process of thermal decomposition of NiSO₄, there might be aggregation of Ni atoms, accompanied by adsorption of carbon species onto the surface simultaneously. We suggest that localized SO₂/O₂ gases be released from NiSO₄ molecules (surrounding Ni atoms), which might segregate or dilute the carbon species, keeping them from dissolving into Ni catalysts to initiate CNT growth. From the SEM and TEM micrographs, we can deduce that the CNF started to form after Ni aggregating into 40–50 nm sized, multifaceted nanoparticles. As a comparison, a SEM micrograph of Ni nanoparticles from direct pyrolysis of as-deposited NiSO₄ at 900 °C for 15 min is shown in Fig. 8a. The sizes of these Ni nanoparticles were in the 50–100 nm range. The shapes were irregularly multifaceted. As shown in Fig. 8b, an irregularly shaped Ni catalyst particle with two downward faces (indicated by the arrows) was embedded in the tip of a CNF. Such downward faces would cause graphene layers to bend, to favor fishbone-type CNF growth. For samples under laser irradiation at 300 mJ/cm², fine (10–20 nm) and nearly spherical NiSO₄ nanoparticles were obtained [Fig. 2(f)]. During the thermal decomposition of NiSO₄, the carbon species can penetrate and dissolve into Ni particles at an earlier
stage to initiate small-diameter CNT growth. As a result, MWCNTs with smaller diameters were preferentially synthesized.

IV. CONCLUSION

We have demonstrated a method to produce Ni nanocatalysts by irradiating dispersed NiSO₄ microclusters on silicon substrates using a KrF excimer laser. The size distributions of clusters/nanoparticles were found to be determined by both laser fluence and pulse number. By increasing laser fluence from 100 to 300 mJ/cm², the average size of disintegrated particles was drastically decreased, from several micrometers to several nanometers. It was suggested that laser-induced disintegration be mainly due to the physical fragmentation by transient thermal expansion/contraction of substrates under pulsed-laser irradiation. The possibility of nanoparticle thermal melting under multipulse irradiation was also suggested. Hot-atom chemical vapor deposition was used for growth of CNTs from pulsed-laser prepared catalysts. For samples irradiated at 100 and 200 mJ/cm², CNFs were dominant products. These CNFs grew radially out of large NiSO₄ clusters, forming dendritic CNF bunches. For catalysts prepared at 300 mJ/cm², multiwalled CNTs with uniform diameters were obtained. We suggest that Ni atoms aggregate through thermal decomposition of NiSO₄ clusters/nanoparticles during HFCVD. The size and the shape of the Ni aggregation, which were determined by the initial size of NiSO₄ clusters/nanoparticles, might affect the preference in the synthesis of CNT or CNFs.

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